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In the claims:

Please cancel claims 8, 13 and 19. Please amend claims 1, 9, 12, 14, 20, 23 and 24. A detailed listing of the claims is as follows.

- 1. (Currently Amended) A biaxially textured article comprising a biaxially textured substrate having thereon at least one epitaxial nitride layer, said article further comprising an electro-magnetic device layer.
- 2. (Original) The biaxially textured article of Claim 1 such that the substrate has a {100}<100> orientation texture.
- 3. (Original) The biaxially textured article of Claim 1 wherein the substrate is a biaxially textured metal or alloy.
- 4. (Original) The biaxially textured article of Claim 1 wherein the substrate is biaxially textured Ni or a Ni alloy.
- 5. (Previously Amended) The biaxially textured article of Claim 1 wherein the nitride layer is selected from TiN, CeN, ZrN, HfN, VN, NbN, NdN, LaN, YN, and AIN.
- 6. (Original) The biaxially textured article of Claim 1 further comprising at least one additional nitride layer.
- 7. (Previously Amended) The biaxially textured article of Claim 1 further comprising an oxide buffer layer selected from MgO, CeO₂, YSZ, LaAlO₃, SrTiO₃, LaNiO₃, Y₂O₃, and RE₂O₃.
 - 8. (Canceled)
- 9. (Currently Amended) The biaxially textured article of Claim 1 wherein said device layer is further comprising a superconducting layer.
- 10. (Original) The biaxially textured article of Claim 1 wherein the substrate is a single crystal metal substrate.

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- 11. (Previously Amended) The biaxially textured article of Claim 10 further comprising an oxide buffer layer selected from MgO, CeO₂, YSZ, LaAlO₃, SrTiO₃, LaNiO₃, Y₂O₃, and RE₂O₃.
- 12. (Currently Amended) The biaxially textured article of Claim 10 wherein said device layer is a superconducting-further comprising an electromagnetic device layer.
 - 13. (Canceled)
- 14. (Currently Amended) A biaxially textured article comprising a biaxially textured substrate having thereon at least one epitaxial layer of composition M1_xM2_yN, where M1 and M2 are metals selected from Ti, Ce, Y, Zr, Hf, V, Nb, Nd, La, and Al, and x and y refer to the atomic compositions of the two metals respectively, said article further comprising an electro-magnetic device layer.
- 15. (Original) The biaxially textured article of Claim 14 such that the substrate has a {100}<100> orientation texture.
- 16. (Original) The biaxially textured article of Claim 14 wherein the substrate is a biaxially textured metal or alloy.
- 17. (Original) The biaxially textured article of Claim 14 wherein the substrate is biaxially textured Ni or a Ni alloy.
- 18. (Previously Amended) The biaxially textured article of Claim 14 further comprising an oxide buffer layer selected from MgO, CeO₂, YSZ, LaAlO₃, SrTiO₃, LaNiO₃, Y₂O₃ and RE₂O₃.
 - 19. (Canceled)
- 20. (Currently Amended) The biaxially textured article of Claim 18 wherein saidfurther comprising an electro-magnetic device layer such as is a superconducting layer.
- 21. (Original) The biaxially textured article of Claim 15 wherein the substrate is a single crystal metal or ceramic substrate.

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- 22. (Previously Amended) The biaxially textured article of Claim 21 further comprising an oxide buffer layer selected from MgO, CeO₂, YSZ, LaAlO₃, SrTiO₃, LaNiO₃, Y₂O₃, and RE₂O₃.
- 23. (Currently Amended) The biaxially textured article of Claim 21 wherein saidfurther comprising an electro-magnetic device layer such as is a superconducting layer.
- 24. (Currently Amended) The biaxially textured article of Claim 22 wherein saidfurther comprising an electro-magnetic device layer such asis a superconducting layer.

Claims 25-37. (Canceled)